

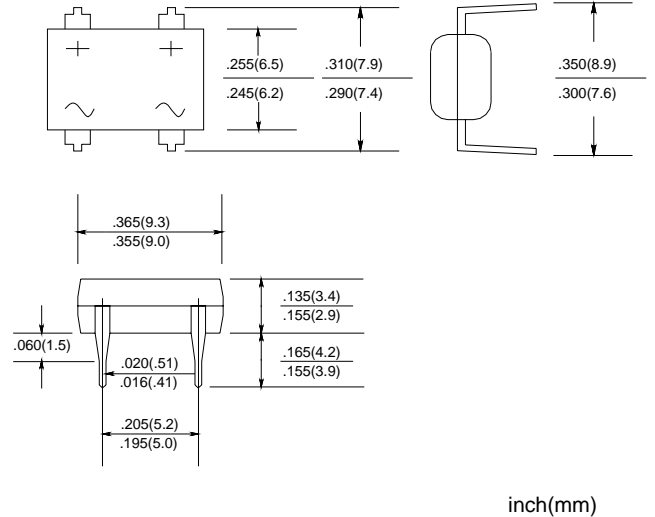
SILICON BRIDGE RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 1.0 A

FEATURES

- ◇ Rating to 1000V PRV
- ◇ Surge overload rating to 30 Amperes peak
- ◇ Ideal for printed circuit board
- ◇ Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- ◇ Lead solderable per MIL-STD-202 method 208
- ◇ Lead: silver plated copper, solderde plated
- ◇ Plastic material has UL flammability classification 94V-O
- ◇ Polarity symbols molded on body
- ◇ Weight: 0.016 ounces,0.45 grams

DB - 1



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		FDB 101	FDB 102	FDB 103	FDB 104	FDB 105	FDB 106	FDB 107	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward Output current @ $T_A=25^\circ C$	$I_{F(AV)}$	1.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I_{FSM}	30.0							A
Maximum instantaneous forward voltage at 1.0 A	V_F	1.3							V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$	I_R	10.0 1.0							μA mA
Maximum reverse recovery time (Note1)	t_{rr}	150			250		500		ns
Operating junction temperature range	T_J	- 55 ---- + 125							$^\circ C$
Storage temperature range	T_{STG}	- 55 ---- + 150							$^\circ C$

NOTE:1. Measured with $I_F=0.5A, I_R=1A, t_{rr}=0.25A$.

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FIG.1 – PEAK FORWARD SURGE CURRENT

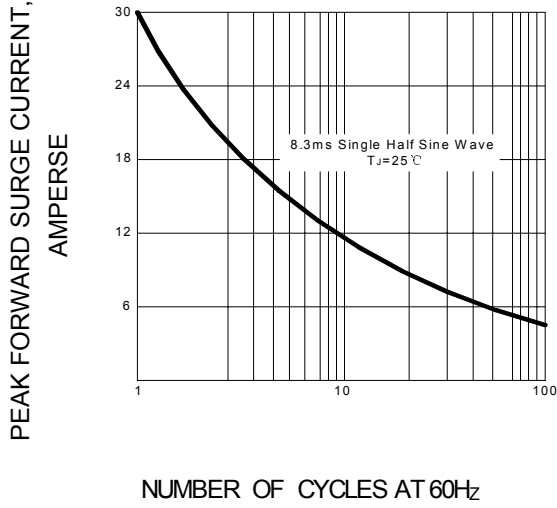


FIG.2 – FORWARD DERATING CURVE

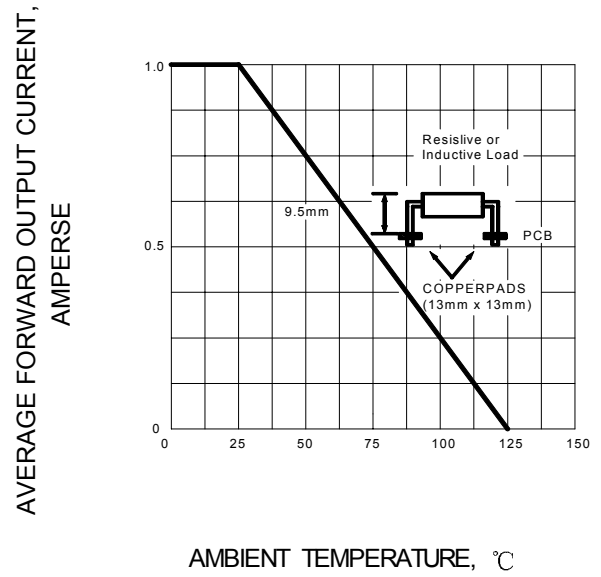


FIG.3 – TYPICAL FORWARD CHARACTERISTIC

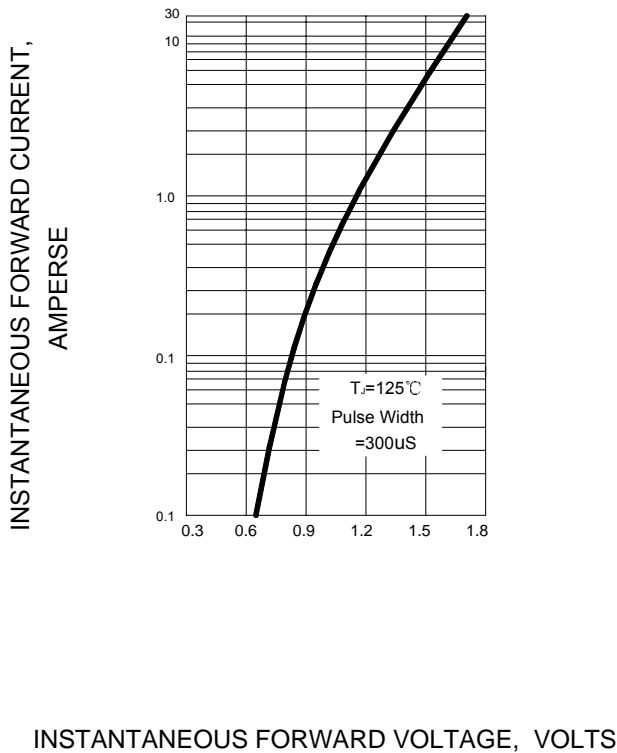


FIG.4 – TYPICAL REVERSE CHARACTERISTIC

